

N-Channel Power MOSFET

80V, 67A, 8.9mΩ

FEATURES

- Low $R_{DS(ON)}$ to minimize conductive losses
- Logic level
- Low gate charge for fast power switching
- 100% UIS and R_g tested
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS

PARAMETER	VALUE	UNIT
V_{DS}	80	V
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	8.9
	$V_{GS} = 4.5V$	11
Q_g	45	nC

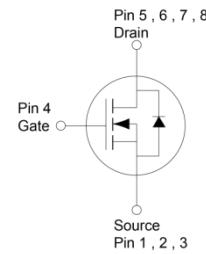
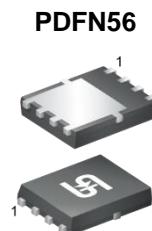
APPLICATIONS

- BLDC Motor Control
- Telecom power
- Primary and Secondary Side Switch



RoHS
COMPLIANT

HALOGEN
FREE



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V_{DS}	80	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ^(Note 1)	I_D	67	A
$T_C = 25^\circ C$		12	
Pulsed Drain Current	I_{DM}	268	A
Single Pulse Avalanche Current ^(Note 2)	I_{AS}	36	A
Single Pulse Avalanche Energy ^(Note 2)	E_{AS}	194	mJ
Total Power Dissipation	P_D	83	W
$T_C = 125^\circ C$		17	
Total Power Dissipation	P_D	2.6	W
$T_A = 125^\circ C$		0.5	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +150	°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	$R_{\Theta JC}$	1.5	°C/W
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	48	°C/W

Thermal Performance Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ C$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV_{DSS}	80	--	--	V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu A$	$V_{GS(TH)}$	1	1.9	2.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 80V$	I_{DSS}	--	--	1	μA
	$V_{GS} = 0V, V_{DS} = 80V$ $T_J = 125^\circ C$		--	--	100	
Drain-Source On-State Resistance (Note 3)	$V_{GS} = 10V, I_D = 12A$	$R_{DS(on)}$	--	6.4	8.9	$m\Omega$
	$V_{GS} = 4.5V, I_D = 12A$		--	8	11	
Forward Transconductance (Note 3)	$V_{DS} = 5V, I_D = 12A$	g_{fs}	--	49	--	S
Dynamic (Note 4)						
Total Gate Charge	$V_{GS} = 10V, V_{DS} = 40V,$ $I_D = 12A$	Q_g	--	90	--	nC
Total Gate Charge	$V_{GS} = 4.5V, V_{DS} = 40V,$ $I_D = 12A$	Q_g	--	45	--	
Gate-Source Charge		Q_{gs}	--	16	--	
Gate-Drain Charge		Q_{gd}	--	23	--	
Input Capacitance	$V_{GS} = 0V, V_{DS} = 40V$ $f = 1.0MHz$	C_{iss}	--	6119	--	pF
Output Capacitance		C_{oss}	--	304	--	
Reverse Transfer Capacitance		C_{rss}	--	116	--	
Gate Resistance	$f = 1.0MHz$	R_g	0.5	1.5	3	Ω
Switching (Note 4)						
Turn-On Delay Time	$V_{GS} = 10V, V_{DS} = 40V,$ $I_D = 12A, R_G = 2\Omega$	$t_{d(on)}$	--	8	--	ns
Turn-On Rise Time		t_r	--	21	--	
Turn-Off Delay Time		$t_{d(off)}$	--	45	--	
Turn-Off Fall Time		t_f	--	24	--	
Source-Drain Diode						
Forward Voltage (Note 3)	$V_{GS} = 0V, I_S = 12A$	V_{SD}	--	--	1	V
Reverse Recovery Time	$I_S = 12A,$ $dI/dt = 100A/\mu s$	t_{rr}	--	33	--	ns
Reverse Recovery Charge		Q_{rr}	--	35	--	nC

Notes:

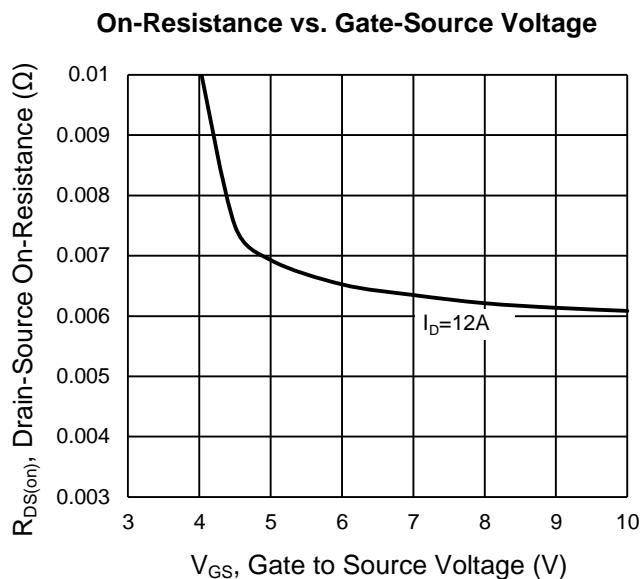
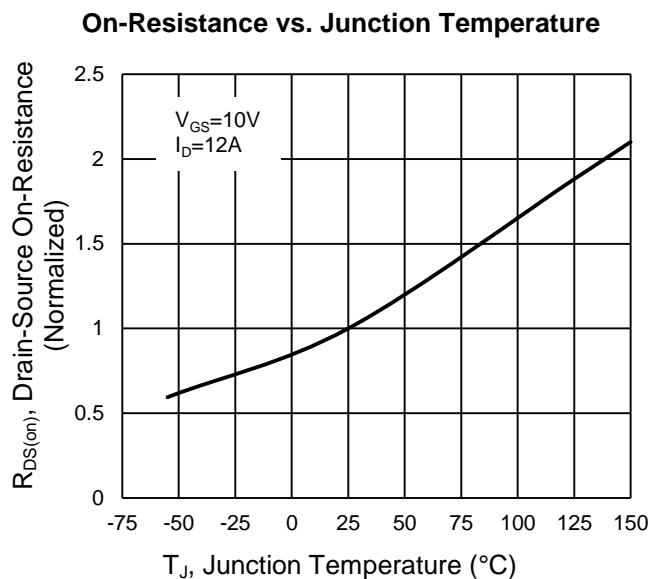
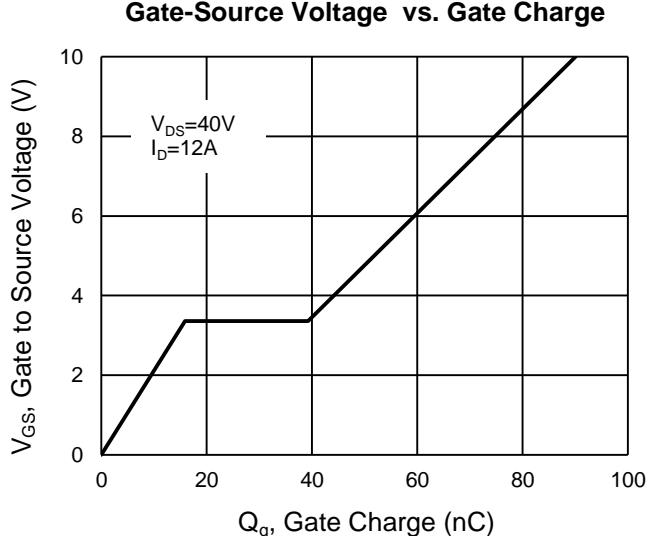
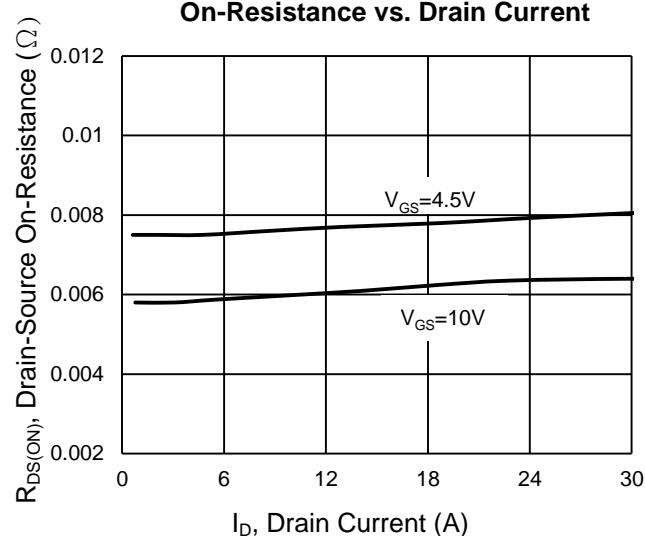
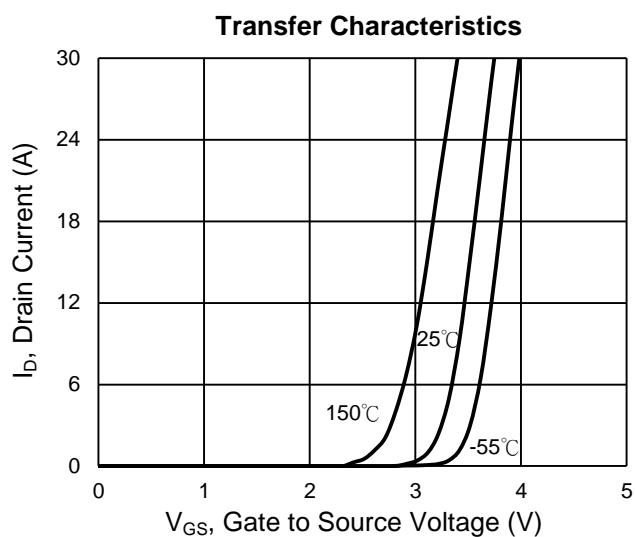
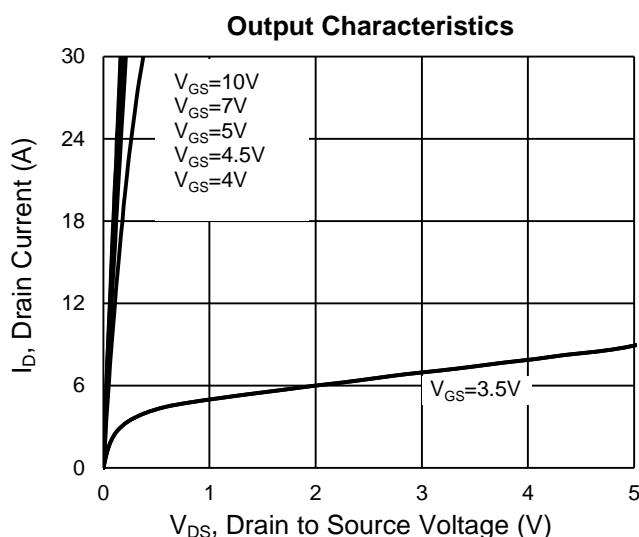
1. Silicon limited current only.
2. $L = 0.3mH, V_{GS} = 10V, V_{DD} = 30V, R_G = 25\Omega, I_{AS} = 36A$, Starting $T_J = 25^\circ C$
3. Pulse test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
4. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM089N08LCR RLG	PDFN56	2,500pcs / 13"Reel

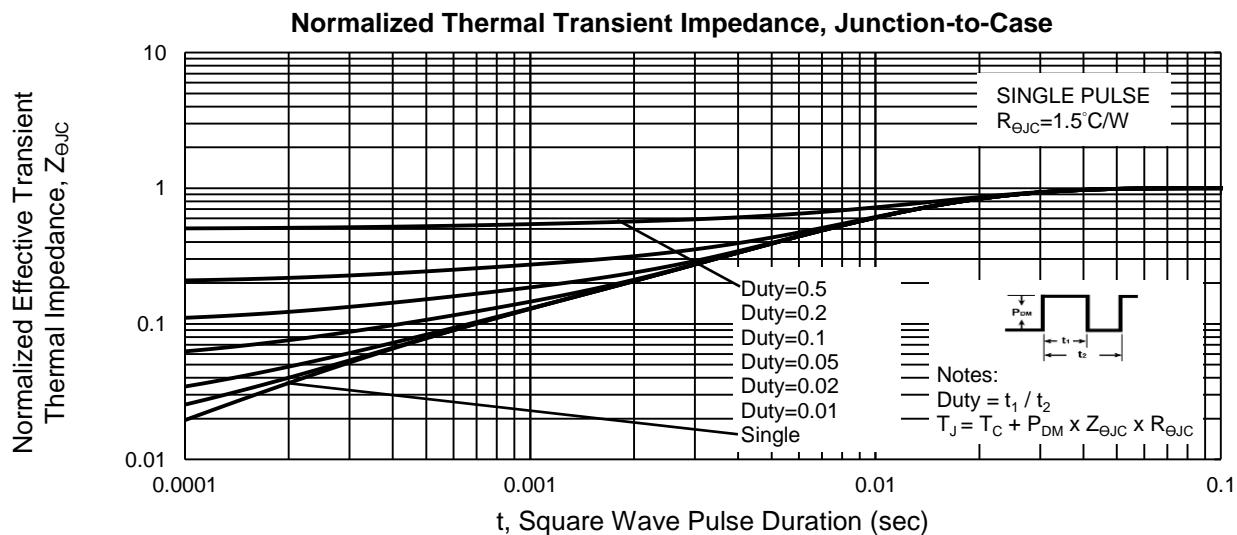
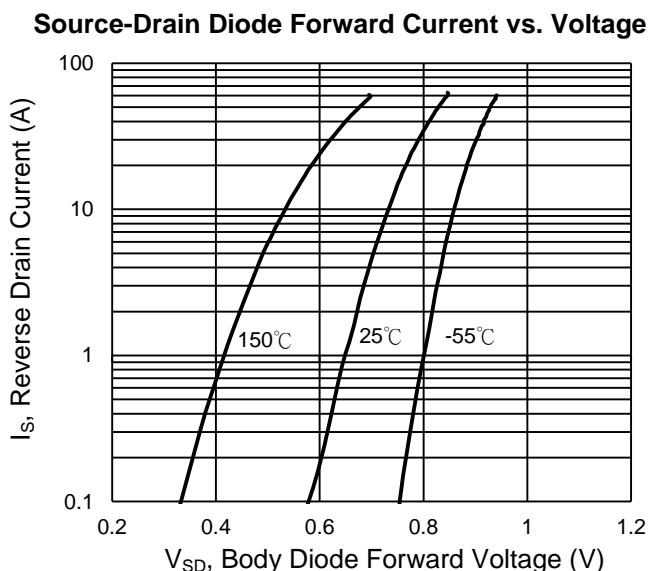
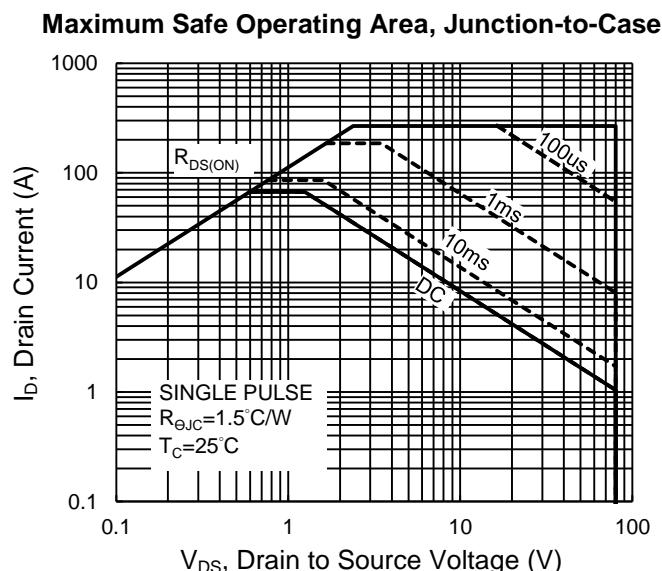
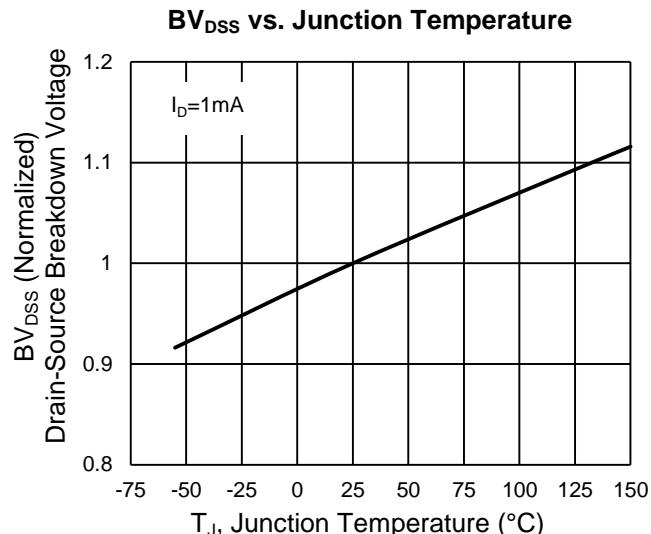
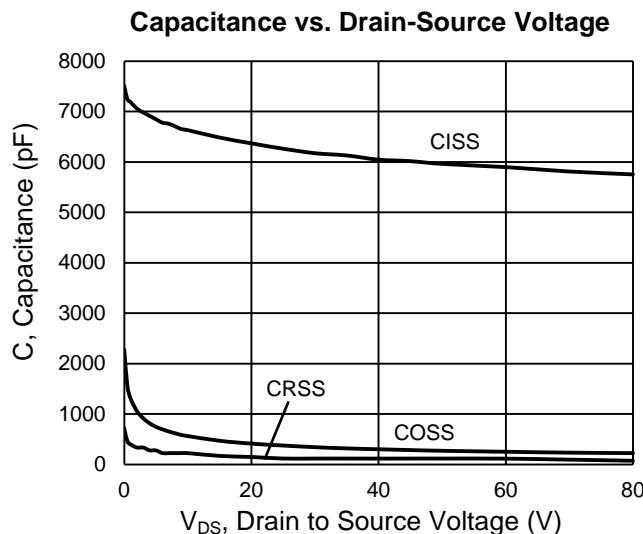
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

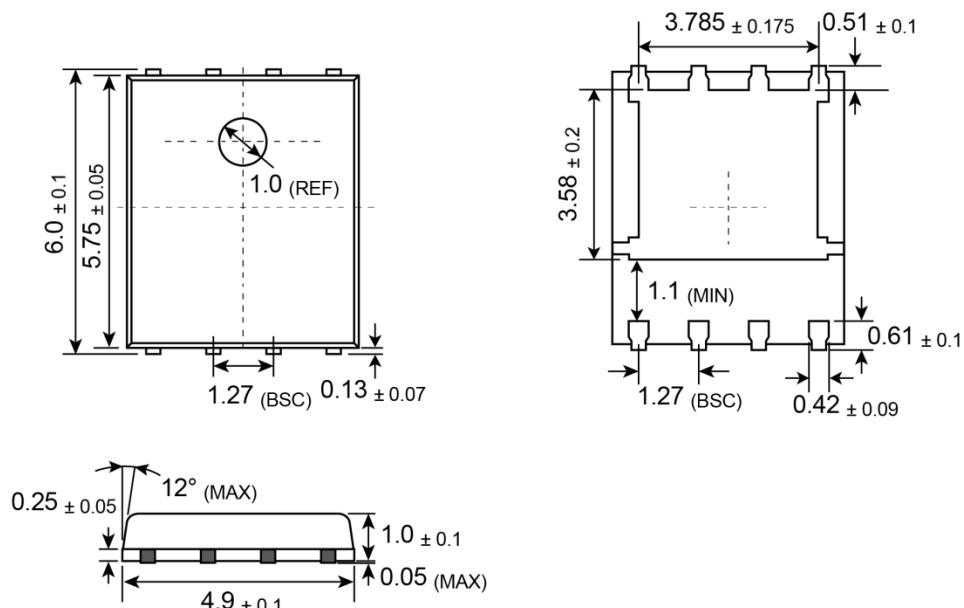
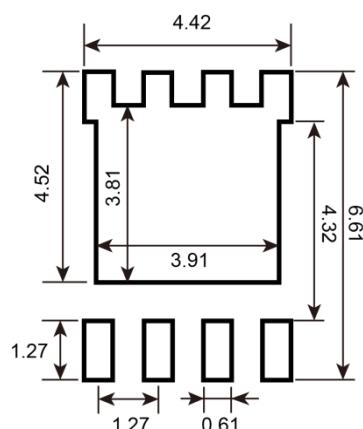


CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

PDFN56

SUGGESTED PAD LAYOUT (Unit: Millimeters)

MARKING DIAGRAM


- G** = Halogen Free
- Y** = Year Code
- WW** = Week Code (01~52)
- F** = Factory Code

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